NSN 5961-01-281-2933

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Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-281-2933 **Inclosure Material:** Metal **Overall Length:** 2.612 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Burn in **Overall Width Across Flats:** 1.056 inches Thread Size: 0.500 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 1200.0 nonrepetitive peak reverse voltage, peak total value, gate terminal open-circuited and 1000.0 repetitive peak reverse voltage, peak total value, gate terminal open-circuited **Current Rating Per Characteristic:** 110.00 amperes forward current, average of standard range and 1500.00 amperes forward current, average preset **Power Rating Per Characteristic:** 2.0 watts small-signal input power, common-collector universal and 10.0 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 tab, solder lug and 1 insulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No